

30V N-Channel Power MOSFET



SOP-8

Pin Definition:



Key Parameter Performance

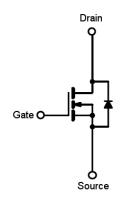
Parameter		Value	Unit	
$V_{ t DS}$		30	V	
	V _{GS} = 10V	4.2	mΩ	
$R_{DS(on)}$ (max)	$V_{GS} = 4.5V$	6		
Q_g		24	nC	

Ordering Information

Part No.	Package	Packing		
TSM042N03CS RLG	SOP-8	2.5kps / 13" Reel		

Note: "G" denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	30	V
Gate-Source Voltage		V _{GS}	±20	V
Continuous Drain Current	Tc=25°C		30	Α
	Tc=100°C	l _D	19	А
Pulsed Drain Current (Note 1)		I _{DM}	I _{DM} 120	
Single Pulse Avalanche Energy (Note 2)		E _{AS}	125	mJ
Single Pulse Avalanche Current (Note 2)		I _{AS}	50	А
Power Dissipation @ T _C = 25°C		P _D	7	W
Operating Junction Temperature		TJ	175	°C
Storage Temperature Range		T _{STG}	-55 to +175	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	R _{OJA}	62	°C/W



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Electrical Specifications (T_J=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	30			V
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 12A$			3.8	4.2	mΩ
	$V_{GS} = 4.5V, I_D = 6A$	$R_{DS(ON)}$		5.2	6	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	V _{GS(TH)}	1.2	1.6	2.5	V
Zero Gate Voltage Drain Current	$V_{DS} = 30V, V_{GS} = 0V$				1	μΑ
	V _{DS} = 24V, T _J = 125°C	I _{DSS}			10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
Forward Transconductance (Note 3)	$V_{DS} = 10V, I_{D} = 6A$	g _{fs}		12		S
Dynamic				l .		
Total Gate Charge (Note 3,4)		Q_g		24		
Gate-Source Charge (Note 3,4)	$V_{DS} = 15V, I_{D} = 12A,$	Q_gs		4.2		nC
Gate-Drain Charge (Note 3,4)	$V_{GS} = 4.5V$	Q _{qd}		13		
Input Capacitance		C _{iss}		2200		pF
Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$	C _{oss}		280		
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		177		
Switching		100		<u> </u>		
Turn-On Delay Time (Note 3,4)		t _{d(on)}		12.6		
Turn-On Rise Time (Note 3,4)	$V_{DD} = 15V, I_D = 15A,$	t _r		19.5		
Turn-Off Delay Time (Note 3,4)	$V_{GS} = 10V, R_{GEN} = 3.3\Omega$	t _{d(off)}		42.8		ns
Turn-Off Fall Time (Note 3,4)		t _f		13.2		
Source-Drain Diode Ratings and Ch	aracteristic		l .			
Maximum Continuous Drain-Source	Integral reverse diode in the MOSFET					
Diode Forward Current		I _S			30	Α
Maximum Pulse Drain-Source Diode		I			120	Α
Forward Current		I _{SM}			120	
Diode Forward Voltage	$V_{GS} = 0V, I_{S} = 1A$	V_{SD}			1	V

Note:

- 1. Pulse width limited by safe operating area
- 2. L=0.1mH, I_{AS} =50A, V_{DD} = 25V, R_G = 25 Ω , Starting T_J = 25 $^{\circ}$ C
- 3. Pulse test: pulse width ≤300µs, duty cycle ≤2%
- 4. Switching time is essentially independent of operating temperature.

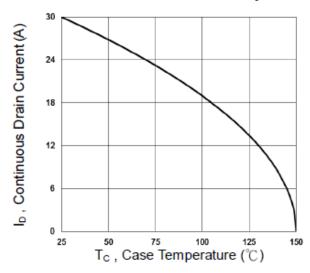


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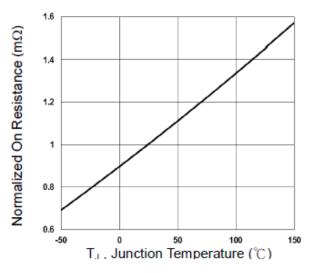


Electrical Characteristics Curve

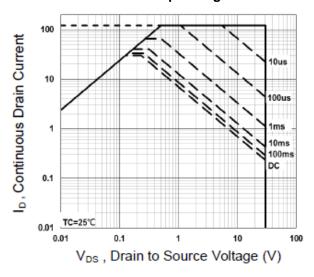
Continuous Drain Current vs. Tc



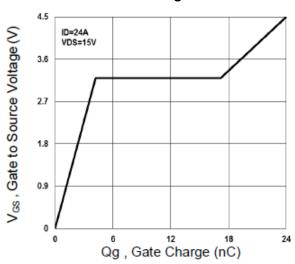
On-Resistance vs. Junction Temperature



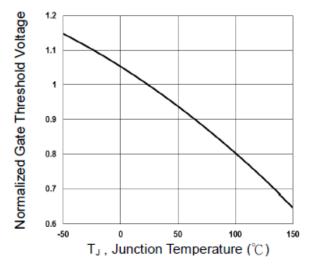
Maximum Safe Operating Area



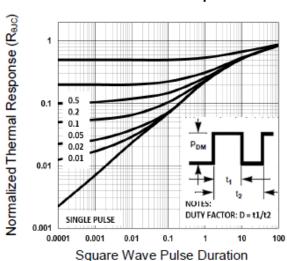
Gate Charge



Threshold Voltage vs. Junction Temperature



Normalized Thermal Transient Impedance Curve

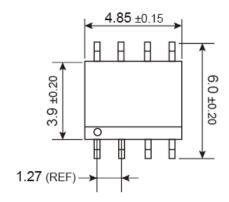


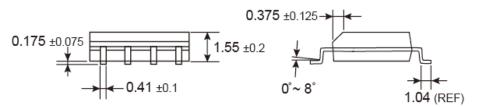


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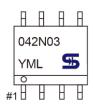
SOP-8 Mechanical Drawing





Unit: Millimeters

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product
 (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

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L = Lot Code

Version: A14



Pb ROHS

TSM042N03CS 30V N-Channel Power MOSFET

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